

TS912, TS912A, TS912B

Rail-to-rail CMOS dual operational amplifier

Features

- Rail-to-rail input and output voltage ranges
- Single (or dual) supply operation from 2.7 to 16 V
- Extremely low input bias current: 1 pA typ.
- Low input offset voltage: 2 mV max.
- Specified for 600 Ω and 100 Ω loads
- Low supply current: 200 μA/amplifier (V_{CC} = 3 V)
- Latch-up immunity
- ESD tolerance: 3 kV
- Spice macromodel included in this specification

Description

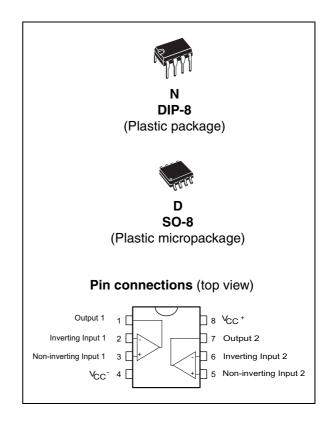
The TS912 is a rail-to-rail CMOS dual operational amplifier designed to operate with a single or dual supply voltage.

The input voltage range V_{icm} includes the two supply rails V_{CC}^+ and V_{CC}^- .

The output reaches V_{CC} +30 mV, V_{CC} + -40 mV, with R_L = 10 k Ω and V_{CC} +300 mV, V_{CC} + -400 mV, with R_L = 600 Ω

This product offers a broad supply voltage operating range from 2.7 to 16 V and a supply current of only 200 μ A/amp (V_{CC} = 3 V).

Source and sink output current capability is typically 40 mA (at V_{CC} = 3 V), fixed by an internal limitation circuit.



1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	18	V
V _{id}	Differential input voltage (2)	±18	V
V _i	Input voltage (3)	-0.3 to 18	V
I _{in}	Current on inputs	±50	mA
Io	Current on outputs	±130	mA
T _{stg}	Storage temperature	-65 to +150	°C
Tj	Maximum junction temperature	150	°C
R _{thja}	Thermal resistance junction to ambient ⁽⁴⁾ DIP8 SO-8	85 125	°C/W
R _{thjc}	Thermal resistance junction to case ⁽⁴⁾ DIP8 SO-8	41 40	°C/W
	HBM: human body model ⁽⁵⁾	3	kV
ESD	MM: machine model ⁽⁶⁾	200	V
	CDM: charged device model ⁽⁷⁾	1500	V

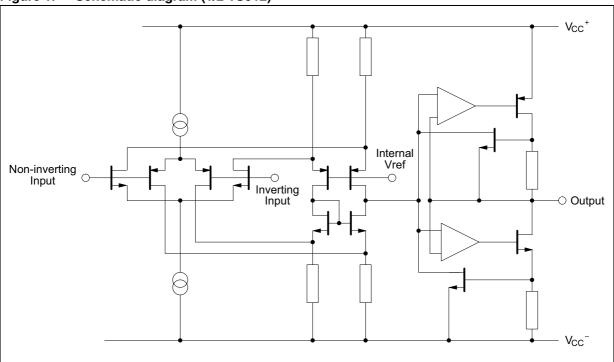
- 1. All voltage values, except differential voltage are with respect to network ground terminal.
- 2. Differential voltages are non-inverting input terminal with respect to the inverting input terminal.
- 3. The magnitude of input and output voltages must never exceed V_{CC}^+ +0.3 V.
- 4. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuits on all amplifiers. These values are typical.
- 5. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 k Ω resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 6. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.</p>
- 7. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V _{CC} Supply voltage		2.7 to 16	V
V _{icm}	Common mode input voltage range	V _{CC-} -0.2 to V _{CC+} +0.2	V
T _{oper}	Operating free air temperature range	-40 to + 125	°C

2 Schematic diagram

Figure 1. Schematic diagram (1/2 TS912)



3 Electrical characteristics

Table 3. $V_{CC+} = 3 \text{ V}, V_{CC-} = 0 \text{ V}, R_L, C_L \text{ connected to } V_{CC}/2, T_{amb} = 25^{\circ}\text{C} \text{ (unless otherwise specified)}$

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ($V_{ic} = V_o = V_{CC}/2$) TS912 TS912A TS912B			10 5 2	mV
10	$T_{min} \le T_{amb} \le T_{max}$ TS912 TS912A TS912B			12 7 3	
ΔV_{io}	Input offset voltage drift		5		μV/°C
I _{io}	Input offset current $^{(1)}$ $T_{min} \le T_{amb} \le T_{max}$		1	100 200	pA
I _{ib}	Input bias current $^{(1)}$ $T_{min} \le T_{amb} \le T_{max}$		1	150 300	pA
I _{CC}	Supply current (per amplifier, $A_{VCL} = 1$, no load) $T_{min} \le T_{amb} \le T_{max}$		200	300 400	μΑ
CMR	Common mode rejection ratio $V_{ic} = 0$ to 3 V, $V_o = 1.5$ V		70		dB
SVR	Supply voltage rejection ratio (V_{CC}^+ = 2.7 to 3.3 V, $V_0 = V_{CC}/2$)	50	80		dB
A _{vd}	Large signal voltage gain (R _L = 10 k Ω , V _o = 1.2 V to 1.8 V) T _{min} \leq T _{amb} \leq T _{max}	3 2	10		V/mV
V _{OH}	High level output voltage (V_{id} = 1 V) R_L = 100 k Ω R_L = 10 k Ω R_L = 600 Ω R_L = 100 Ω $T_{min} \le T_{amb} \le T_{max}$	2.95 2.9 2.3	2.96 2.6 2		V
	$R_{L} = 10 \text{ k}\Omega$ $R_{L} = 600 \Omega$	2.8 2.1			
V _{OL}	Low level output voltage (V_{id} = -1 V) $R_L = 100 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$ $R_L = 100 \Omega$		30 300 900	50 70 400	mV
	$\begin{aligned} T_{min} &\leq T_{amb} \leq T_{max} \\ R_{L} &= 10 \text{ k}\Omega \\ R_{L} &= 600 \Omega \end{aligned}$			100 600	
I _o	Output short-circuit current ($V_{id} = \pm 1 \text{ V}$) Source ($V_o = V_{CC-}$) Sink ($V_o = V_{CC+}$)	20 20	40 40		mA
GBP	Gain bandwidth product $(A_{VCL} = 100, R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF, f} = 100 \text{ kHz})$		0.8		MHz

Table 3. $V_{CC+} = 3 \text{ V}, V_{CC-} = 0 \text{ V}, R_L, C_L \text{ connected to } V_{CC}/2, T_{amb} = 25^{\circ}\text{C} \text{ (unless otherwise specified) (continued)}$

Symbol	Parameter	Min.	Тур.	Max.	Unit
SR ⁺	Slew rate (A _{VCL} = 1, R _L = 10 k Ω , C _L = 100 pF, V _i = 1.3 V to 1.7 V)		0.4		V/µs
SR ⁻	Slew rate (A _{VCL} = 1, R _L = 10 k Ω , C _L = 100 pF, V _i = 1.3 V to 1.7 V)		0.3		V/μs
φm	Phase margin		30		Degrees
en	Equivalent input noise voltage ($R_s = 100 \Omega f = 1 \text{ kHz}$)		30		nV/√Hz

^{1.} Maximum values include unavoidable inaccuracies of the industrial tests.

Table 4. $V_{CC+} = 5 \text{ V}, V_{CC-} = 0 \text{ V}, R_L, C_L \text{ connected to } V_{CC}/2, T_{amb} = 25^{\circ}\text{C} \text{ (unless otherwise specified)}$

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage (V _{ic} = V _o = V _{CC} /2) TS912 TS912A TS912B			10 5 2	mV
	$T_{min} \le T_{amb} \le T_{max}$ $TS912$ $TS912A$ $TS912B$			12 7 3	
ΔV_{io}	Input offset voltage drift		5		μV/°C
I _{io}	Input offset current $^{(1)}$ $T_{min} \le T_{amb} \le T_{max}$		1	100 200	pA
I _{ib}	Input bias current $^{(1)}$ $T_{min} \le T_{amb} \le T_{max}$		1	150 300	pA
I _{cc}	Supply current (per amplifier, A_{VCL} = 1, no load) $T_{min} \le T_{amb} \le T_{max}$		230	350 450	μΑ
CMR	Common mode rejection ratio $V_{ic} = 1.5$ to 3.5 V, $V_o = 2.5$ V	60	85		dB
SVR	Supply voltage rejection ratio ($V_{CC+} = 3 \text{ to } 5 \text{ V}, V_0 = V_{CC}/2$)	55	80		dB
A _{vd}	Large signal voltage gain (R _L = 10 k Ω V _o = 1.5 V to 3.5 V) $T_{min} \le T_{amb} \le T_{max}$	10 7	40		V/mV
V _{OH}	High level output voltage (V_{id} = 1V) $R_L = 100 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$ $R_L = 100 \Omega$ $T_{min} \le T_{amb} \le T_{max}$ $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$	4.95 4.9 4.25 4.8 4.1	4.95 4.55 3.7		V
V _{OL}	Low level output voltage (V_{id} = -1 V) R_L = 100 k Ω R_L = 10 k Ω R_L = 600 Ω R_L = 100 Ω $T_{min} \le T_{amb} \le T_{max}$ R_L = 10 k Ω R_L = 600 Ω		40 350 1400	50 100 500 150 750	mV
I _o	Output short-circuit current ($V_{id} = \pm 1 \text{ V}$) Source ($V_o = V_{CC-}$) Sink ($V_o = V_{CC+}$)	45 45	65 65		mA
GBP	Gain bandwidth product (A _{VCL} = 100, R _L = 10 k Ω , C _L = 100 pF, f = 100 kHz)		1		MHz
SR ⁺	Slew rate (A _{VCL} = 1, R _L = 10 k Ω , C _L = 100 pF, V _i = 1 V to 4 V)		0.8		V/µs
SR ⁻	Slew rate (A _{VCL} = 1, R _L = 10 k Ω , C _L = 100 pF, V _i = 1 V to 4 V)		0.6		V/μs

Table 4. $V_{CC+} = 5 \text{ V}, V_{CC-} = 0 \text{ V}, R_L, C_L \text{ connected to } V_{CC}/2, T_{amb} = 25^{\circ}\text{C} \text{ (unless otherwise specified) (continued)}$

Symbol	Parameter	Min.	Тур.	Max.	Unit
en	Equivalent input noise voltage ($R_s = 100 \Omega f = 1 \text{ kHz}$)		30		nV/√Hz
V _{O1} /V _{O2}	Channel separation (f = 1 kHz)		120		dB
φm	Phase margin		30		Degrees

^{1.} Maximum values include unavoidable inaccuracies of the industrial tests.

Table 5. $V_{CC+} = 10 \text{ V}, V_{CC-} = 0 \text{ V}, R_L, C_L \text{ connected to } V_{CC}/2, T_{amb} = 25^{\circ}\text{C} \text{ (unless otherwise specified)}$

Symbol	Parameter	Min.	Тур.	Max.	Unit
V	Input offset voltage ($V_{ic} = V_o = V_{CC}/2$) TS912 TS912A TS912B			10 5 2	mV
V _{io}	$T_{min} \le T_{amb} \le T_{max}$ TS912 TS912A TS912B			12 7 3	IIIV
ΔV_{io}	Input offset voltage drift		5		μV/°C
I _{io}	Input offset current ⁽¹⁾ T _{min} ≤ T _{amb} ≤ T _{max}		1	100 200	pA
l _{ib}	Input bias current $^{(1)}$ $T_{min} \le T_{amb} \le T_{max}$		1	150 300	pA
I _{CC}	Supply current (per amplifier, A_{VCL} = 1, no load) $T_{min} \le T_{amb} \le T_{max}$		400	600 700	μΑ
CMR	Common mode rejection ratio $V_{ic} = 3$ to 7 V, $V_o = 5$ V $V_{ic} = 0$ to 10 V, $V_o = 5$ V	60 50	90 75		dB
SVR	Supply voltage rejection ratio ($V_{CC+} = 5$ to 10 V, $V_0 = V_{CC}/2$)	60	90		dB
A _{vd}	Large signal voltage gain (R _L = 10 k Ω V _o = 2.5 V to 7.5 V) T _{min} \leq T _{amb} \leq T _{max}	15 10	50		V/mV
V _{OH}	High level output voltage (V_{id} = 1V) $R_L = 100 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$ $R_L = 100 \Omega$ $T_{min} \le T_{amb} \le T_{max}$ $R_L = 10 \text{ k}\Omega$	9.95 9.85 9	9.95 9.35 7.8		>
	$R_L^L = 600 \Omega$	8.8			
V _{OL}	Low level output voltage (V_{id} = -1 V) $R_L = 100 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$ $R_L = 100 \Omega$		50 650 2300	50 150 800	mV
	$T_{min} \le T_{amb} \le T_{max}$ $R_{L} = 10 \text{ k}\Omega$ $R_{L} = 600 \Omega$			150 900	
I _o	Output short circuit current ($V_{id} = \pm 1 \text{ V}$) Source ($V_o = V_{CC-}$) Sink ($V_o = V_{CC+}$)	45 50	65 75		mA
GBP	Gain bandwidth product $(A_{VCL} = 100, R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF}, f = 100 \text{ kHz})$		1.4		MHz

Table 5. $V_{CC+} = 10 \text{ V}, V_{CC-} = 0 \text{ V}, R_L, C_L \text{ connected to } V_{CC}/2, T_{amb} = 25^{\circ}\text{C} \text{ (unless otherwise specified) (continued)}$

Symbol	Parameter	Min.	Тур.	Max.	Unit
SR ⁺	Slew rate $(A_{VCL}=1,\ R_L=10\ k\Omega,\ C_L=100\ pF,\ V_i=2.5\ V\ to\ 7.5\ V)$		1.3		V/μs
SR ⁻	Slew rate (A _{VCL} = 1, R _L = 10 k Ω , C _L = 100 pF, V _i = 2.5 V to 7.5 V)		0.8		V/μs
φm	Phase margin		40		Degrees
en	Equivalent input noise voltage ($R_s = 100 \Omega f = 1 \text{ kHz}$)		30		nV/√Hz
THD	Total harmonic distortion (A _{VCL} = 1, R _L = 10 k Ω C _L = 100 pF, V _o = 4.75 V to 5.25 V, f = 1 kHz)		0.02		%
C _{in}	Input capacitance		1.5		pF

^{1.} Maximum values include unavoidable inaccuracies of the industrial tests.

Figure 2. Supply current (each amplifier) vs. supply voltage

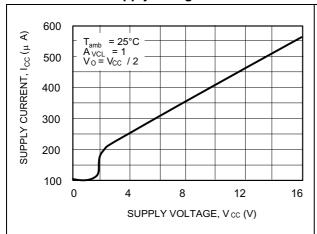


Figure 3. High level output voltage vs. high level output current

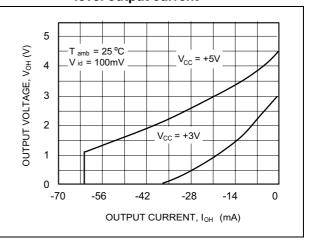


Figure 4. Low level output voltage vs. low level output current

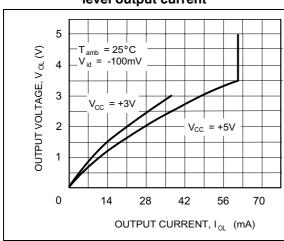


Figure 5. Input bias current vs. temperature

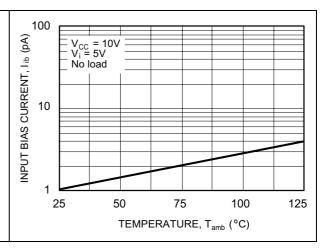


Figure 6. High level output voltage vs. high level output current

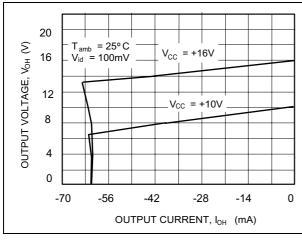
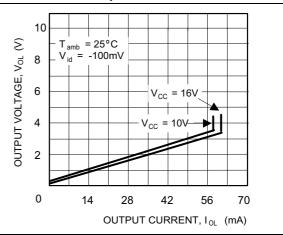


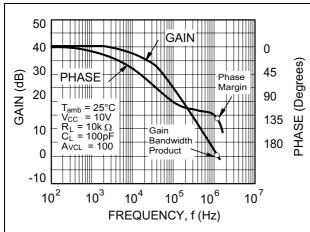
Figure 7. Low level output voltage vs. low level output current



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Figure 8. Gain and phase vs. frequency

Figure 9. Gain bandwidth product vs. supply voltage



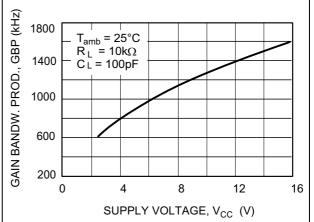
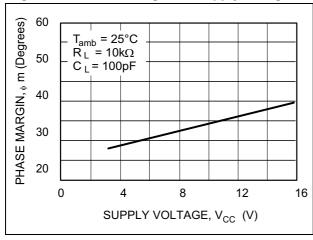


Figure 10. Phase margin vs. supply voltage

Figure 11. Gain and phase vs. frequency



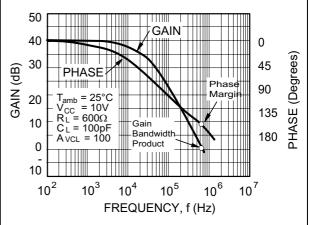
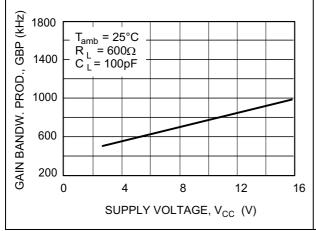
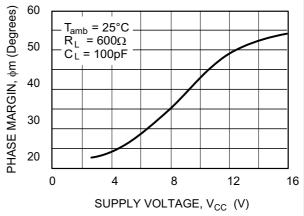


Figure 12. Gain bandwidth product vs. supply Figure 13. Phase margin vs. supply voltage voltage





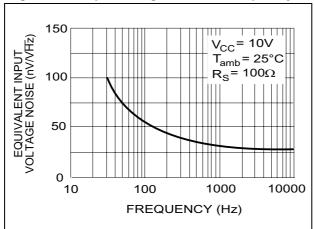


Figure 14. Input voltage noise vs. frequency

4 Macromodel

4.1 Important note concerning this macromodel

- All models are a trade-off between accuracy and complexity (i.e. simulation time).
- Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.
- A macromodel emulates the nominal performance of a typical device within specified operating conditions (temperature, supply voltage, for example). Thus the macromodel is often not as exhaustive as the datasheet, its purpose is to illustrate the main parameters of the product.

Data derived from macromodels used outside of the specified conditions (V_{CC} , temperature, for example) or even worse, outside of the device operating conditions (V_{CC} , V_{icm} , for example), is not reliable in any way.

4.2 Macromodel code

```
** Standard Linear Ics Macromodels, 1993.
** CONNECTIONS :
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY
.SUBCKT TS912 1 2 3 4 5
**************
.MODEL MDTH D IS=1E-8 KF=6.563355E-14 CJO=10F
* INPUT STAGE
CIP 2 5 1.500000E-12
CIN 1 5 1.500000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 6.500000E+00
RIN 15 16 6.500000E+00
RIS 11 15 7.655100E+00
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 0.000000E+00
VOFN 13 14 DC 0
IPOL 13 5 4.000000E-05
CPS 11 15 3.82E-08
DINN 17 13 MDTH 400E-12
VIN 17 5 -0.5000000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 -0.5000000E+00
FCP 4 5 VOFP 7.750000E+00
FCN 5 4 VOFN 7.750000E+00
* AMPLIFYING STAGE
FIP 5 19 VOFP 5.500000E+02
FIN 5 19 VOFN 5.500000E+02
RG1 19 5 5.087344E+05
RG2 19 4 5.087344E+05
CC 19 29 2.200000E-08
HZTP 30 29 VOFP 12.33E+02
HZTN 5 30 VOFN 12.33E+02
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 3135
VIPM 28 4 150
HONM 21 27 VOUT 3135
VINM 5 27 150
EOUT 26 23 19 5 1
VOUT 23 5 0
ROUT 26 3 65
COUT 3 5 1.000000E-12
DOP 19 68 MDTH 400E-12
VOP 4 25 1.924
```

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HSCP 68 25 VSCP1 1E8 DON 69 19 MDTH 400E-12 VON 24 5 2.4419107 HSCN 24 69 VSCN1 1.5E8 VSCTHP 60 61 0.1375 DSCP1 61 63 MDTH 400E-12 VSCP1 63 64 0 ISCP 64 0 1.000000E-8 DSCP2 0 64 MDTH 400E-12 DSCN2 0 74 MDTH 400E-12 ISCN 74 0 1.00000E-8 VSCN1 73 74 0 DSCN1 71 73 MDTH 400E-12 VSCTHN 71 70 -0.75 ESCP 60 0 2 1 500 ESCN 70 0 2 1 -2000 .ENDS

5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

5.1 DIP8 package information

Figure 15. DIP8 package mechanical drawing

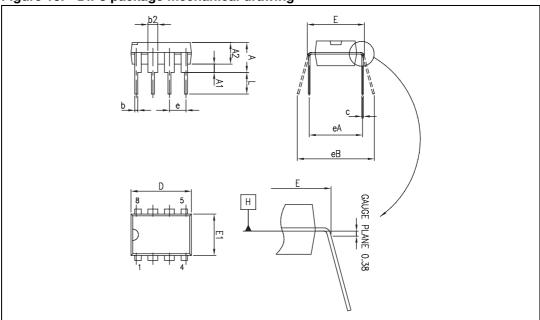


Table 6. DIP8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
С	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
е		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

5.2 SO-8 package information

Figure 16. SO-8 package mechanical drawing

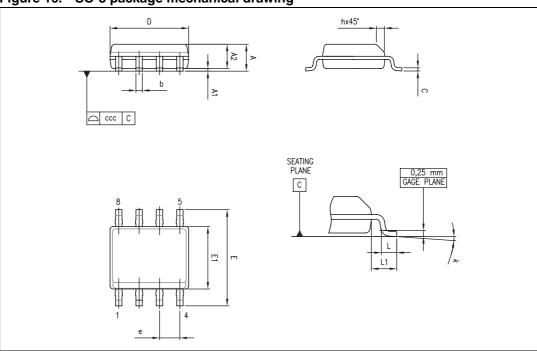


Table 7. SO-8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
С	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	0		8°	1°		8°
ccc			0.10			0.004

6 Ordering information

Table 8. Order codes

Part number	Temperature range	Package	Packing	Marking
TS912IN		DIP8	Tube	TS912IN
TS912AIN		DIFO	lube	TS912AIN
TS912ID TS912IDT				9121
TS912AID TS912AIDT		SO-8		912AI
TS912BID TS912BIDT	-40°C, +125°C		Tube or	912BI
TS912IYD TS912IYDT ⁽¹⁾			Tape & reel	912IY
TS912AIYD TS912AIYDT ⁽¹⁾		SO-8 (Automotive grade level)		912AIY
TS912BIYD TS912BIYDT ⁽¹⁾				912BY

Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

7 Revision history

Table 9. Document revision history

Date	Revision	Changes
04-Dec-2001	1	First release.
31-Jul-2005	2	PPAP references inserted in the datasheet, see order codes table. ESD protection inserted in AMR table.
03-Oct-2005	3	Some errors in the Order Codes table were corrected. Reorganization of Section 4: Macromodel.
13-Feb- 2006	4	Parameters added in AMR table (T_j , ESD, R_{thja} , R_{thjc}).
16-Oct-2007	5	Corrected units and ESD footnotes in <i>Table 1: Absolute maximum ratings</i> . Corrected misalignments in electrical characteristics table. Updated <i>Section 4: Macromodel</i> . Added missing automotive grade order codes and footnote in <i>Table 8: Order codes</i> . Format update.
01-Feb-2010	6	Added TS912A and TS912B part numbers on cover page.

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